

TGS 2616-C00 - for the detection of Hydrogen

Features:

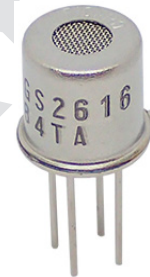
- * High selectivity to hydrogen
- * Small size and low power consumption
- * Uses simple electrical circuit

Applications:

- * Hydrogen detection for:
 - transformer oil maintenance
 - steel plant safety, etc.
- * Portable gas detectors
- * Leak detection for gas appliances
- * Hydrogen leak detectors for fuel cells

The sensing element is comprised of a metal oxide semiconductor layer formed on an alumina substrate of a sensing chip together with an integrated heater, and it is housed in a standard TO-5 package. In the presence of a detectable gas, the sensor's conductivity increases depending on the gas concentration in the air. A simple electrical circuit can convert the change in conductivity to an output signal which corresponds to the gas concentration.

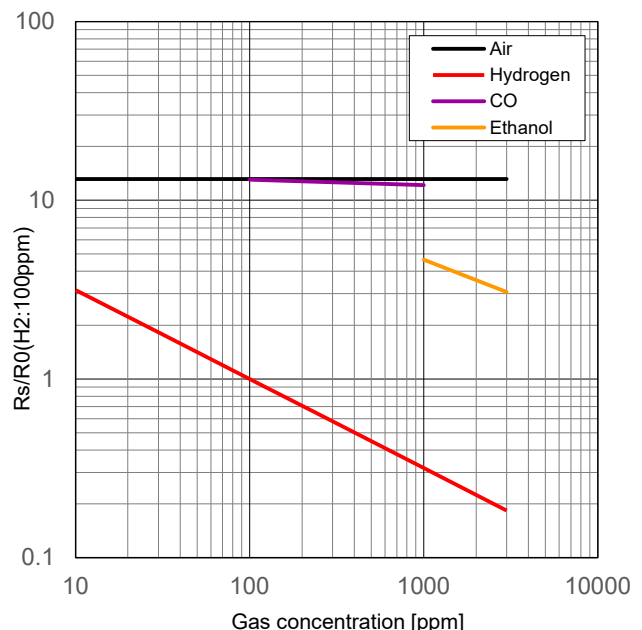
TGS2616-C00 has a newly developed sensing element which reduces the influence of interference gases such as alcohol, resulting in highly selective response to hydrogen.



Sensitivity Characteristics:

The figure on the right represents typical sensitivity characteristics that are measured at standard test conditions. (see reverse side of this sheet for more details) The Y-axis is indicated as sensor resistance ratio R_s/R_0 , where R_s and R_0 are defined as below:

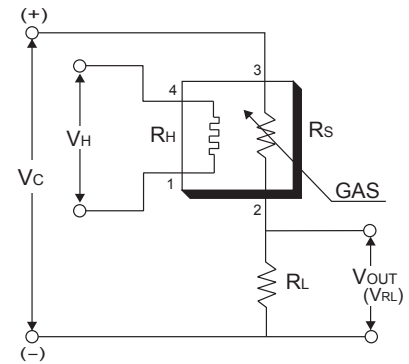
R_s = Sensor resistance in various gases and concentrations
 R_0 = Sensor resistance in 100 ppm of hydrogen



Basic Measuring Circuit:

The sensor requires two voltage inputs: heater voltage (V_H) and circuit voltage (V_C). The heater voltage (V_H) is applied to the integrated heater in order to maintain the sensing element at a specific temperature which is optimal for sensing. Circuit voltage (V_C) is applied to allow measurement of voltage $V_{OUT}(V_{RL})$ across a load resistor (R_L) which is connected in series with the sensor.

A common power supply circuit can be used for both V_C and V_H to fulfill the sensor's electrical requirements. The value of the load resistor (R_L) should be chosen to optimize the alarm threshold value, keeping power dissipation (P_S) of the semiconductor below a limit of 15mW. Power dissipation (P_S) will be highest when the value of R_S is equal to R_L on exposure to gas.



Specifications:

Model number		TGS2616-C00	
Sensing principle		MOS type	
Standard package		TO-5 metal can	
Target gases		Hydrogen	
Typical detection range		10~3000ppm	
Standard circuit conditions	Heater voltage	V_H	5.0±0.2V DC
	Circuit voltage	V_C	5.0±0.2V DC $P_S \leq 15mW$
	Load resistance	R_L	variable 0.45kΩ min.
Electrical characteristics under standard test conditions	Heater resistance	R_H	approx 59Ω at room temp.
	Heater current	I_H	56±5mA
	Heater power consumption	P_H	280mW $V_H = 5.0V$ DC
	Sensor resistance	R_S	0.3kΩ ~ 8.0kΩ in 100ppm hydrogen
Sensitivity (change ratio of R_S)		0.14~0.52	$\frac{R_S(300ppm)}{R_S(30ppm)}$
Standard test conditions	Test gas conditions	Hydrogen in air at 20±2°C, 65±5%RH	
	Circuit conditions	$V_C = 5.0 \pm 0.01V$ DC $V_H = 5.0 \pm 0.05V$ DC	
	Preheating period before test	7 days	

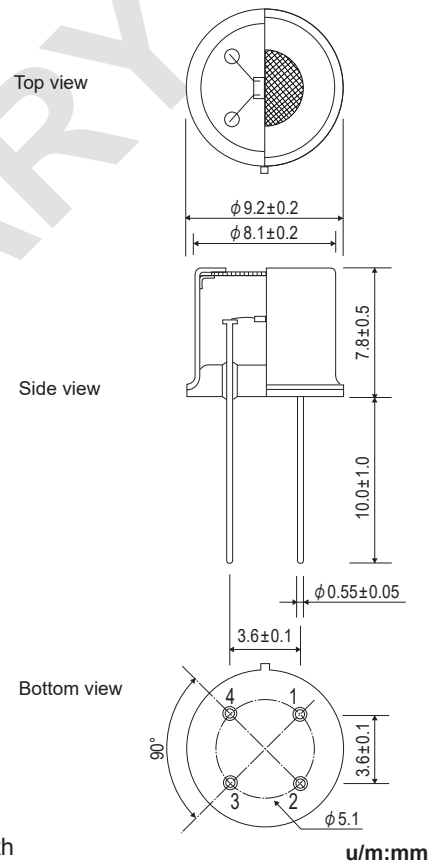
The value of power dissipation (P_S) can be calculated by utilizing the following formula:

$$P_S = \frac{(V_C - V_{RL})^2}{R_S}$$

Sensor resistance (R_S) is calculated with a measured value of $V_{OUT}(V_{RL})$ by using the following formula:

$$R_S = \left(\frac{V_C}{V_{RL}} - 1 \right) \times R_L$$

Structure and Dimensions:



u/m:mm

Pin connection:

- 1: Heater
- 2: Sensor electrode (-)
- 3: Sensor electrode (+)
- 4: Heater

All sensor characteristics shown in this brochure represent typical characteristics. Actual characteristics vary from sensor to sensor. The only characteristics warranted are those in the Specification table above.

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